FREE



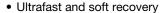
Vishay Semiconductors

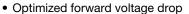
Ultrafast Rectifier, 30 A FRED Pt®

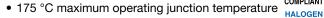


PRIMARY CHARACTERISTICS				
I _{F(AV)}	30 A			
V_{R}	1200 V			
V _F at I _F at 125 °C	2.05 V			
t _{rr}	49 ns			
T_J max.	175 °C			
Package	TO-220AC 2L			
Circuit configuration	Single			

FEATURES







Polyimide passivation

- · Rugged design
- Good thermal performance
- Meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

Ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, recovery time, and soft recovery. Polyimide passivated, planar structure, and the platinum doped life time control guarantee, ruggedness, reliability characteristics, and solid value proposition for efficiency and thermal performance.

These devices are intended for use in boost stage in the AC/DC section of SMPS, high frequency output rectification of battery charger, inverters for solar inverters, or as freewheeling diodes in motor drive.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Repetitive peak reverse voltage	V_{RRM}		1200	V
Average rectified forward current	I _{F(AV)}	T _C = 100 °C, D = 0.50	30	Α
Repetitive peak forward current	I _{FRM}		60	Α
Non-repetitive peak surge current	I _{FSM}	$T_C = 25$ °C, $t_p = 10$ ms, sine wave	240	А
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS MIN. T		TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 500 μA	1200	-	-	.,,
Forward voltage	V	I _F = 30 A	-	2.15	2.68	V
	V _F	I _F = 30 A, T _J = 125 °C	-	2.05	2.45	
Reverse leakage current I _R	I_	$V_R = V_R$ rated	-	-	145	
	'R	T _J = 125 °C, V _R = V _R rated	-	-	320	μΑ
Junction capacitance	C _T	V _R = 200 V	ı	29	-	pF
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nΗ



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	49	-	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	220	-	ns
		T _J = 125 °C	$I_F = 30 \text{ A}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$ $V_R = 390 \text{ V}$	-	356	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	8.2	-	Α
		T _J = 125 °C		-	13.3	-	
Reverse recovery charge Q	0	T _J = 25 °C		-	900	-	nC
	Q _{rr}	T _J = 125 °C		-	2388	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R _{thJC}		-	-	0.8	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	54	°C/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	-	0.4	
Weight			-	2	-	g
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Marking device		Case style: TO-220AC 2L		30E	ΓU12	

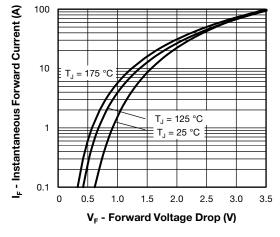


Fig. 1 - Typical Forward Voltage Drop Characteristics

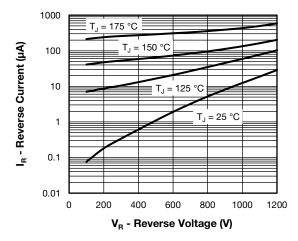


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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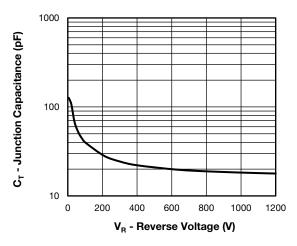


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

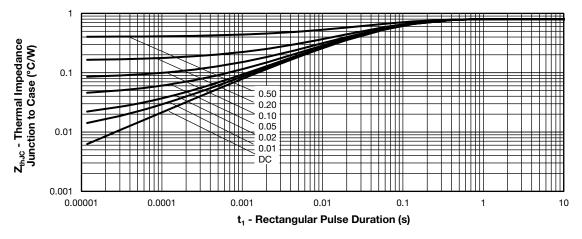


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

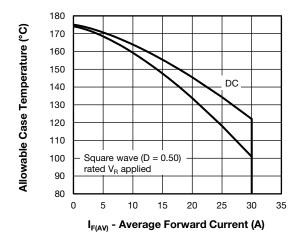


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

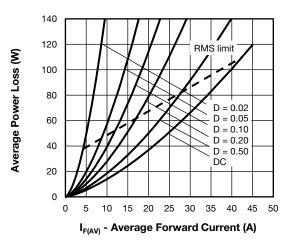


Fig. 6 - Forward Power Loss Characteristics

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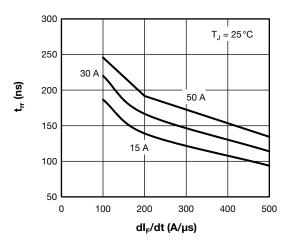


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

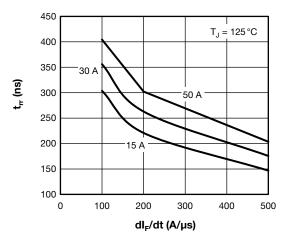


Fig. 8 - Typical Reverse Recovery Time vs. dl_F/dt

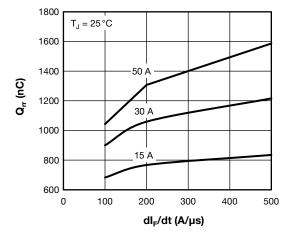


Fig. 9 - Typical Stored Charge vs. dI_F/dt

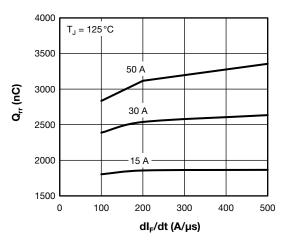


Fig. 10 - Typical Stored Charge vs. dl_F/dt

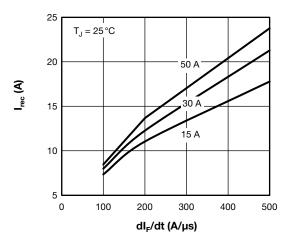


Fig. 11 - Typical Reverse Current vs. dl_F/dt

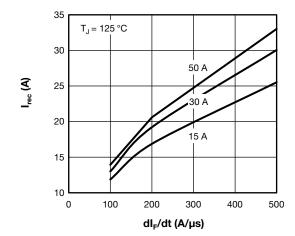
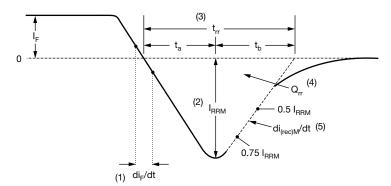


Fig. 12 - Typical Reverse Current vs. dl_F/dt

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- (1) di_F/dt rate of change of current through zero crossing
- (2) $\mathrm{I}_{\mathrm{RRM}}$ peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_{rr}$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

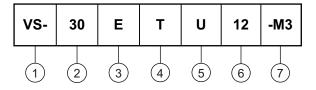
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 13 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- Current rating 30 = 30 A
- 3 E = single diode
- Package: T = TO-220AC
- U = ultrafast recovery
- 6 Voltage rating (12 = 1200 V)
- 7 Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-30ETU12-M3	50	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96156				
Part marking information	www.vishay.com/doc?95391				



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